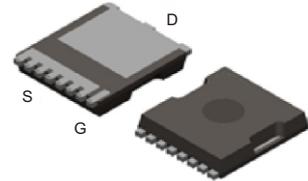


# ACMS300N10T8-HF

**N-Channel**  
**RoHS Device**  
**Halogen Free**



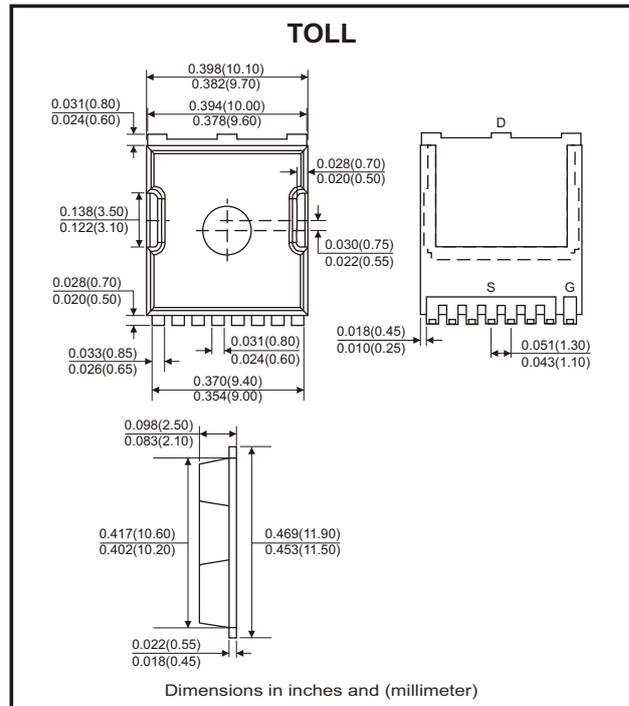
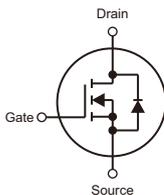
## Features

- Ultra-low on-resistance and gate-charge.
- Advanced shielded-gate technology.
- AEC-Q101 Qualified.

## Mechanical data

- Case: TOLL, molded plastic.
- Terminals: Matte tin-plated leads, solderability-per MIL-STD-202, method 208.
- Mounting position: Any.

## Circuit Diagram



## Maximum Ratings (at TA=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V <sub>DS</sub>	100	V
Gate-source voltage	V <sub>GS</sub>	±20	V
Continuous drain current (T <sub>c</sub> =25°C)	I <sub>D</sub>	300	A
Continuous drain current (T <sub>c</sub> =100°C)	I <sub>D</sub>	210	
Continuous drain current (T <sub>A</sub> =25°C) (Note 1)	I <sub>D</sub>	33	
Continuous drain current (T <sub>A</sub> =100°C) (Note 1)	I <sub>D</sub>	23	
Pulsed drain current @t <sub>p</sub> =10μs, T <sub>c</sub> =25°C	I <sub>DM</sub>	1200	A
Single pulse avalanche energy (Note 3)	E <sub>AS</sub>	3500	mJ
Power dissipation (T <sub>c</sub> =25°C)	P <sub>D</sub>	300	W
Operating junction temperature range	T <sub>J</sub>	-55 to +175	°C
Storage temperature range	T <sub>STG</sub>	-55 to +175	°C

## Thermal Characteristics

Parameter	Symbol	Min	Typ	Max	Unit
Thermal resistance junction to case	R <sub>θJC</sub>		0.4	0.5	°C/W
Thermal resistance junction to air (Note 1)	R <sub>θJA</sub>		24	40	°C/W

## Electrical Characteristics (at T<sub>J</sub>=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	100			V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V			5	μA
Gate-body leakage current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20, V <sub>DS</sub> = 0V			±100	nA
<b>On Characteristics</b>						
Static drain-source on-resistance (Note 2)	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 150A		1.3	1.6	mΩ
	R <sub>DS(on)</sub>	V <sub>GS</sub> = 6V, I <sub>D</sub> = 75A		1.7	2.2	mΩ
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	2	3	4	V
Gate resistance	R <sub>G</sub>	V <sub>GS</sub> = 0V, f = 1MHz		2		Ω
<b>Dynamic Characteristics</b>						
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 50V, f = 1MHz		13113		pF
Output capacitance	C <sub>oss</sub>			2167		
Reverse transfer capacitance	C <sub>rss</sub>			25		
<b>Switching Characteristics</b>						
Turn-on delay time (Note 4)	t <sub>d(on)</sub>	V <sub>DD</sub> = 50V, V <sub>GS</sub> = 10V R <sub>G</sub> = 1.8Ω, I <sub>D</sub> = 100A		20		ns
Turn-on rise time (Note 4)	t <sub>r</sub>			13		
Turn-off delay time (Note 4)	t <sub>d(off)</sub>			49		
Turn-off fall time (Note 4)	t <sub>f</sub>			17		
Total gate charge	Q <sub>g</sub>	V <sub>DD</sub> = 50V, V <sub>GS</sub> = 10V, I <sub>D</sub> = 100A		211		nC
Gate to source charge	Q <sub>gs</sub>			57		
Gate to drain (miller) charge	Q <sub>gd</sub>			59		
<b>Source-Drain Diode Characteristics</b>						
Diode forward voltage (Note 2)	V <sub>SD</sub>	I <sub>S</sub> = 100A, V <sub>GS</sub> = 0V		0.8	1.2	V
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 40A, V <sub>GS</sub> = 0V, di/dt = 100A/μs		118		ns
Reverse recovery charge	Q <sub>rr</sub>			346		nC

- Notes: 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.  
 2. The data tested by pulsed, pulse width ≤ 300μs, duty cycle ≤ 2%.  
 3. The EAS data shows max. rating. The test condition is V<sub>DD</sub>=80V, V<sub>GS</sub>=10V, L=50mH.  
 4. Guaranteed by design, not subject to production.

## Typical Rating and Characteristic Curves (ACMS300N10T8-HF)

Fig.1 - Power Dissipation

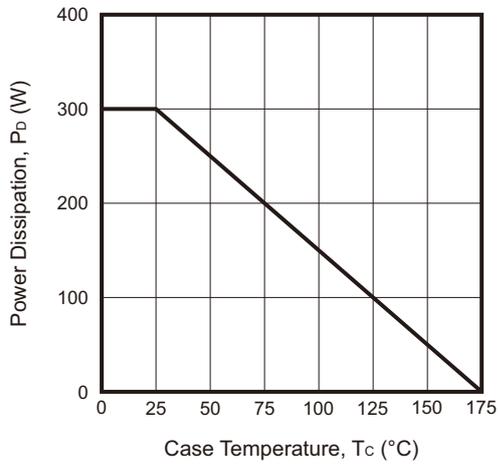


Fig.2 - Drain Current

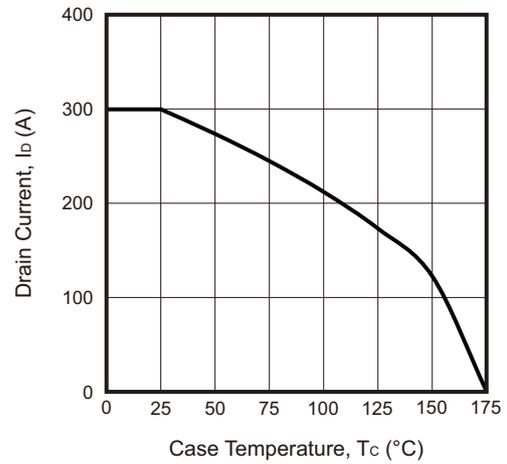


Fig.3 - Typical Output Characteristics

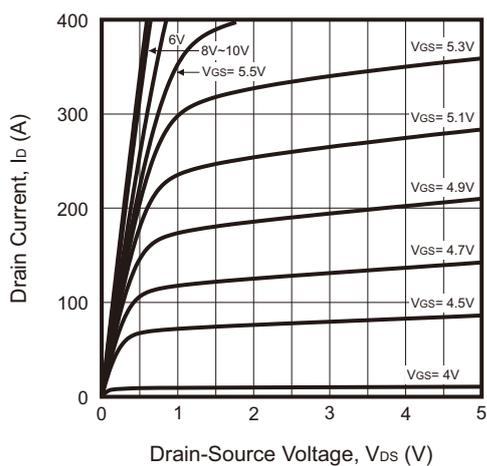


Fig.4 - On-Resistance vs. Drain Current and Gate Voltage

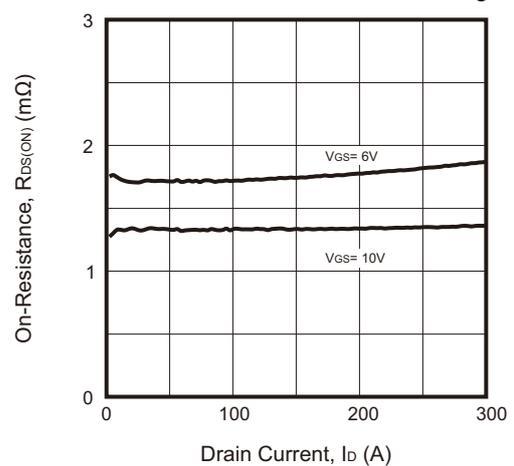


Fig.5 - On-Resistance vs. Gate-Source Voltage

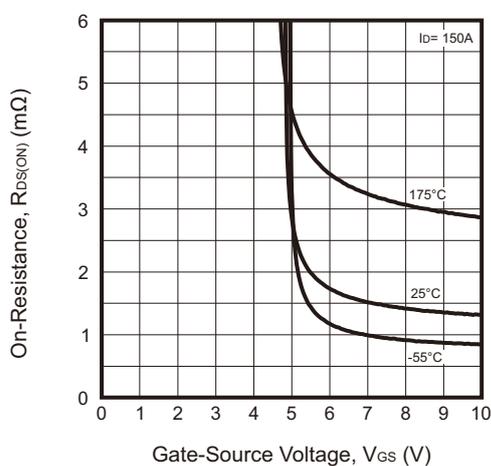
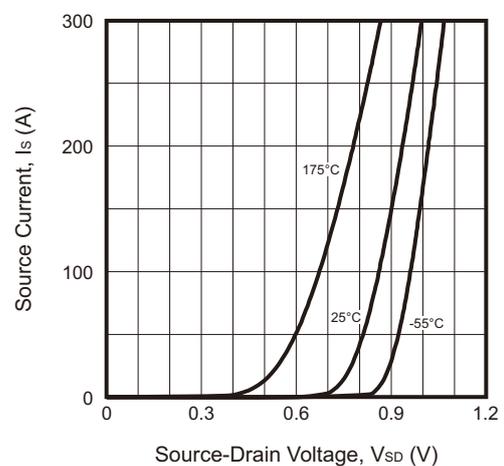
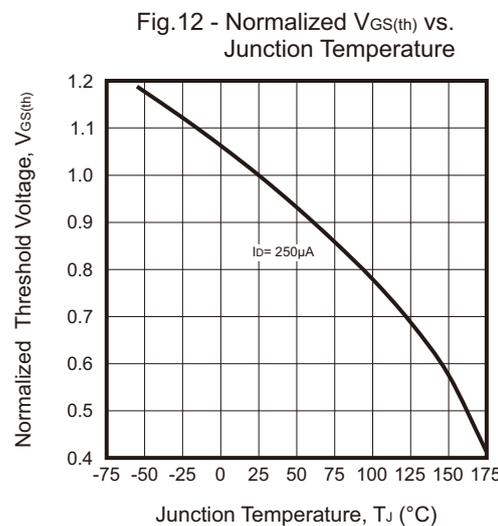
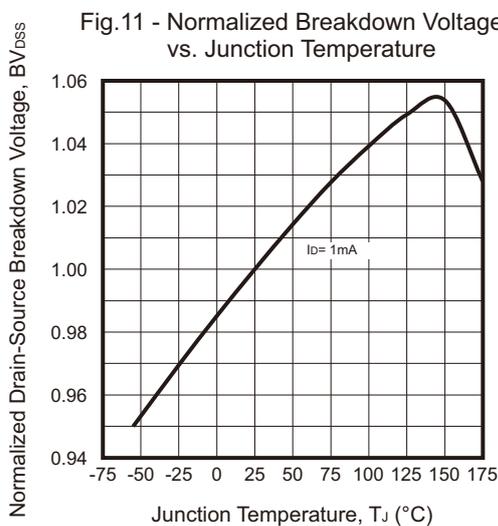
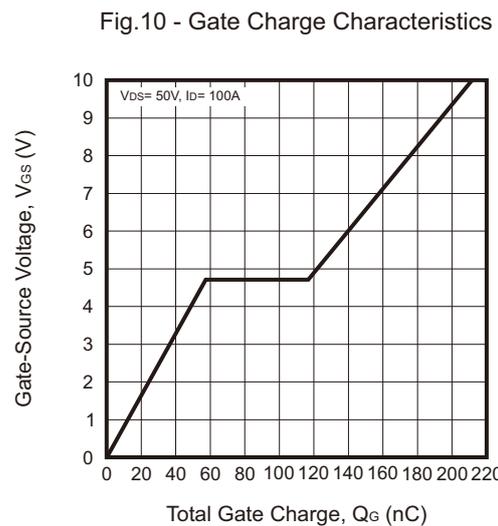
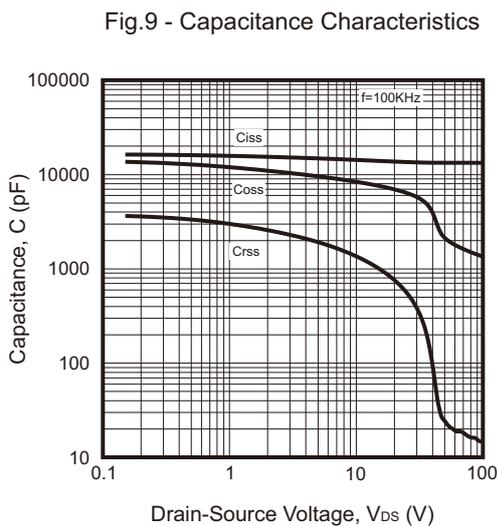
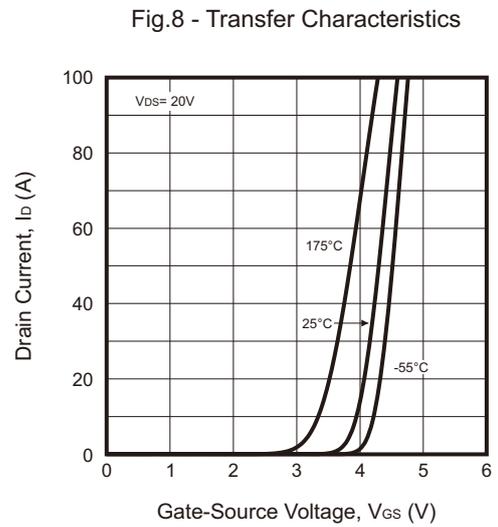
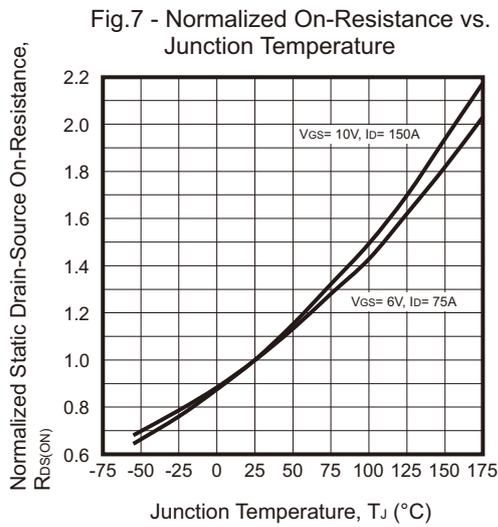


Fig.6 - Body-Diode Characteristics

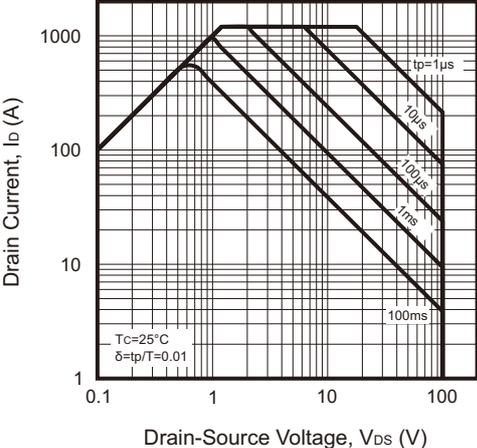


## Typical Rating and Characteristic Curves (ACMS300N10T8-HF)

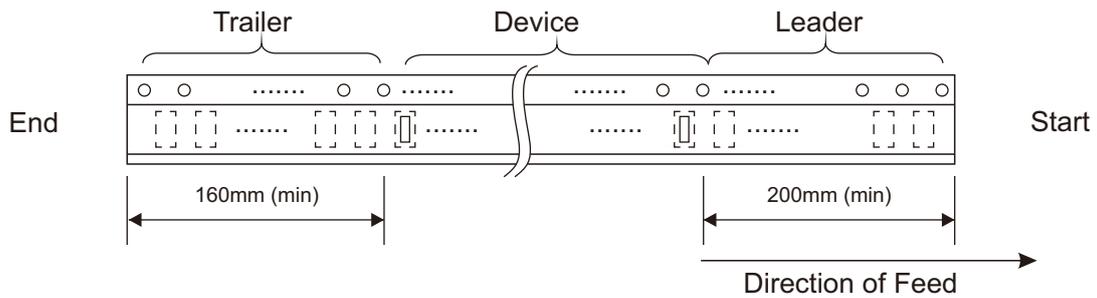
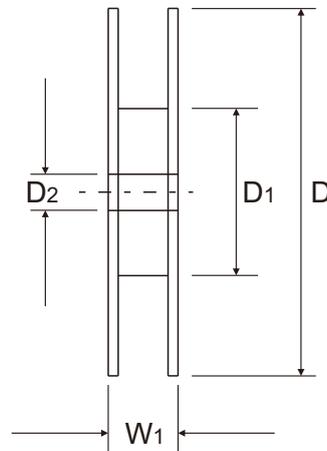
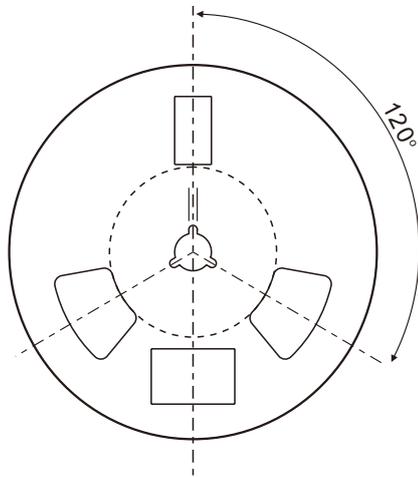
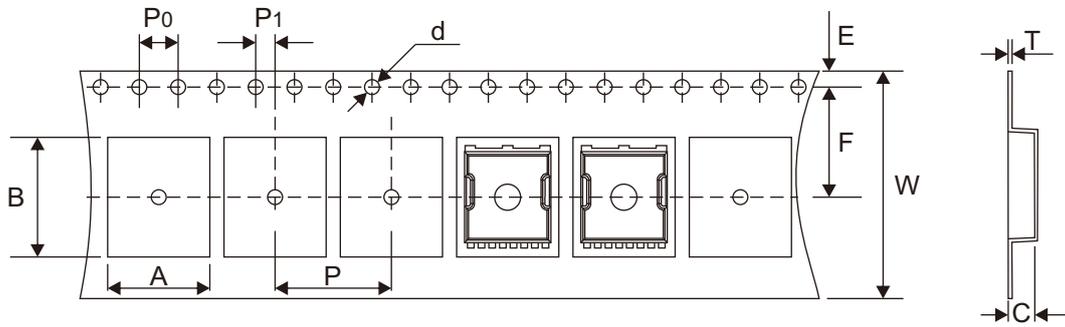


Typical Rating and Characteristic Curves (ACMS300N10T8-HF)

Fig.13 - Safe Operating Area



Reel Taping Specification

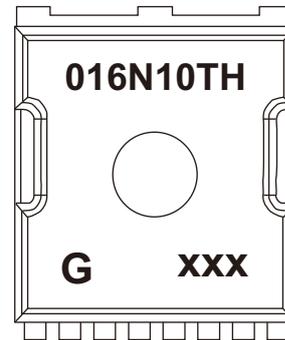


TOLL	SYMBOL	A	B	C	d	D	D <sub>1</sub>	D <sub>2</sub>
	(mm)	10.50 ± 0.10	12.28 ± 0.10	2.70 ± 0.10	1.50 + 0.10 - 0.00	330.00 ± 0.20	100.00 ± 0.20	21.00 ± 0.40
	(inch)	0.413 ± 0.004	0.483 ± 0.004	0.106 ± 0.004	0.061 + 0.004 - 0.000	12.992 ± 0.008	3.937 ± 0.008	0.827 ± 0.016

TOLL	SYMBOL	E	F	P	P <sub>0</sub>	P <sub>1</sub>	T	W	W <sub>1</sub>
	(mm)	1.75 ± 0.10	11.50 ± 0.10	12.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	0.30 ± 0.05	24.00 ± 0.30	24.00 ± 0.20
	(inch)	0.069 ± 0.004	0.453 ± 0.004	0.472 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.012 ± 0.002	0.945 ± 0.012	0.945 ± 0.008

## Marking Code

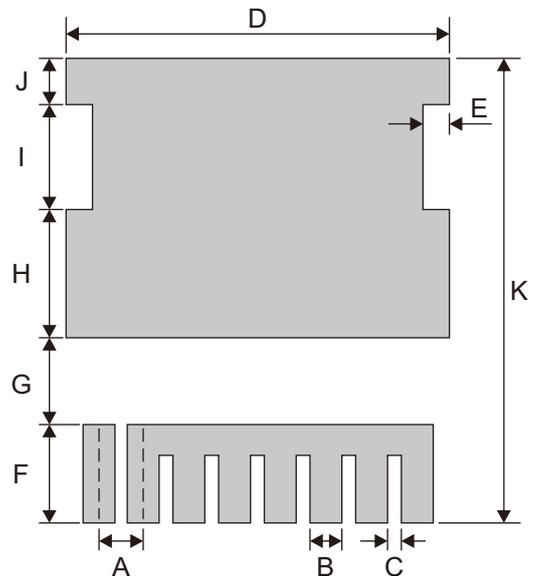
Part Number	Marking Code
ACMS300N10T8-HF	016N10TH



XXX = Control code

## Suggested P.C.B. PAD Layout

SIZE	TOLL	
	(mm)	(inch)
A	1.20	0.047
B	0.80	0.031
C	0.40	0.016
D	10.10	0.398
E	0.70	0.028
F	2.80	0.110
G	2.50	0.098
H	3.70	0.146
I	2.90	0.114
J	1.40	0.055
K	13.30	0.524



## Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
TOLL	2,000	13